

PMEG3002TV

$0.2~\mathrm{A}~\mathrm{very}~\mathrm{low}~\mathrm{V_F}~\mathrm{MEGA}~\mathrm{Schottky}~\mathrm{barrier}~\mathrm{dual}~\mathrm{rectifier}~\mathrm{in}~\mathrm{SOT}666~\mathrm{package}$

Rev. 02 — 15 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier dual rectifier with an integrated guard ring for stress protection, encapsulated in a SOT666 ultra small and flat lead Surface Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		Configuration
	NXP	JEITA	
PMEG3002TV	SOT666	-	dual isolated

1.2 Features

Forward current: ≤ 0.2 A

Reverse voltage: ≤ 30 V

Very low forward voltage

Ultra small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	-	0.2	Α
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	$I_F = 200 \text{ mA}$	[2] _	420	480	mV

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$





2. Pinning information

Table 3. Pinning

	9		
Pin	Description	Simplified outline	Symbol
1	anode (diode 1)		
2	not connected	6 5 4	6 5 4
3	cathode (diode 2)		\frac{1}{2} \qquad \frac{1}{2} \qquad
4	anode (diode 2)		
5	not connected	1 2 3	1 2 3 <i>006aaa440</i>
6	cathode (diode 1)	1 2 3	

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PMEG3002TV	-	plastic surface mounted package; 6 leads	SOT666

4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG3002TV	2M



5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	N	V lin	Max	Unit
Per diod	le					
V_R	reverse voltage		-		30	V
l _F	forward current	$T_{amb} \le 25 ^{\circ}C$	[1] -		0.2	Α
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$	-		1	Α
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	[1] -		2.5	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1] _		200	mW
	total power discipation ramb		[2] _		300	mW
Per devi	ce					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1] _		300	mW
			[2] _		400	mW
Tj	junction temperature		-		150	°C
T _{amb}	ambient temperature		_	-65	+150	°C
T _{stg}	storage temperature		_	-65	+150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device	9						
ιι (j α)	thermal resistance from	in free air	[1][2]	-	-	416	K/W
	junction to ambient		[1][3]	-	-	318	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[4]</u>	-	-	195	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating are available on request.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[4] Soldering point of cathode tab.



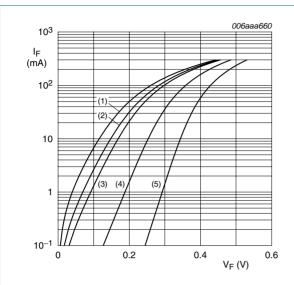
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

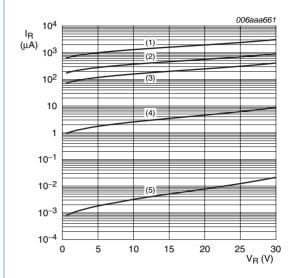
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V _F	forward voltage		[1]			
		$I_F = 0.1 \text{ mA}$	-	130	190	mV
	I _F = 1 mA	-	190	250	mV	
	I _F = 10 mA	-	255	300	mV	
	I _F = 100 mA	-	355	400	mV	
	I _F = 200 mA	-	420	480	mV	
I _R	reverse current	V _R = 10 V	-	3	10	μΑ
		V _R = 30 V	-	10	30	μΑ
		$V_R = 10 \text{ V}; T_{amb} = 100 ^{\circ}\text{C}$	-	400	-	μΑ
C _d	diode capacitance	$V_R = 1 V; f = 1 MHz$	-	20	25	pF

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



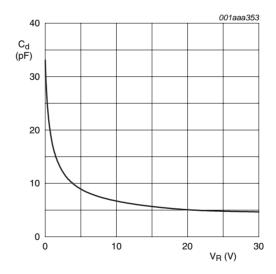
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) T_{amb} = 100 °C
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 100 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



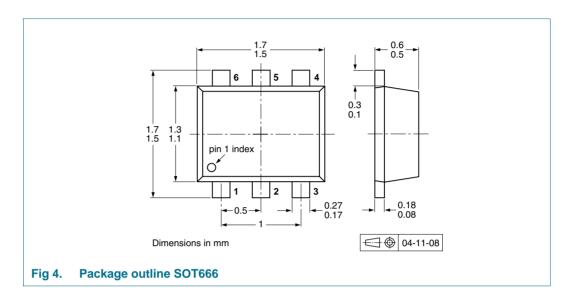
 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

6 of 10

0.2 A very low V_F MEGA Schottky barrier dual rectifier

Package outline 8.



Packing information

Product data sheet

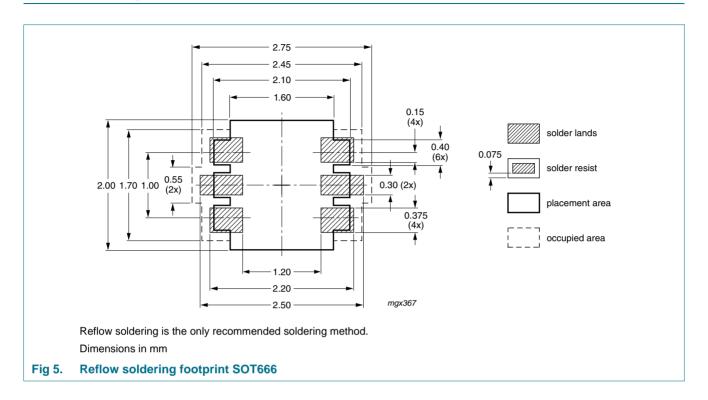
Table 9. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qua	ntity
			4000	8000
PMEG3002TV SOT666	2 mm pitch, 8 mm tape and reel	-	-315	
		4 mm pitch, 8 mm tape and reel	-115	-

[1] For further information and the availability of packing methods, see Section 13.

10. Soldering





11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3002TV_2	20100115	Product data sheet	-	PMEG3002TV_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PMEG3002TV_1	20051021	Product data sheet	-	-



12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	3
6	Thermal characteristics	3
7	Characteristics	4
8	Package outline	6
9	Packing information	6
10	Soldering	7
11	Revision history	8
12	Legal information	9
12.1	Data sheet status	9
12.2	Definitions	9
12.3	Disclaimers	9
12.4	Trademarks	9
13	Contact information	9
14	Contents	0

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